

Description

The SX10P06MSI uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

General Features

$V_{DS} = -60V$ $I_D = -10A$

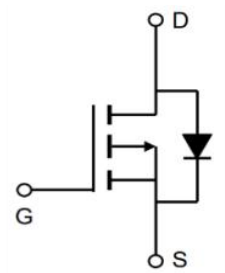
$R_{DS(ON)} < 70m\Omega$ @ $V_{GS}=10V$

Application

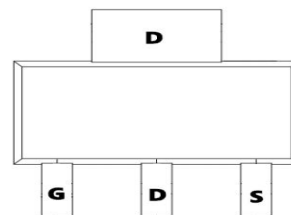
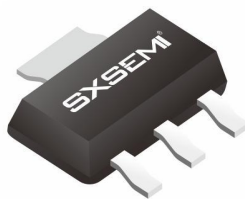
Brushless motor

Load switch

Uninterruptible power supply



SOT-223-3L



Absolute Maximum Ratings ($T_c=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	-60	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D @ T_A=25^\circ\text{C}$	Continuous Drain Current, V_{GS} @ -10V ¹	-10	A
$I_D @ T_A=70^\circ\text{C}$	Continuous Drain Current, V_{GS} @ -10V ¹	-3	A
I_{DM}	Pulsed Drain Current ²	-30	A
I_{AS}	Avalanche Current	-26.6	A
$P_D @ T_A=25^\circ\text{C}$	Total Power Dissipation ⁴	1.5	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ\text{C}$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance Junction-Ambient ¹	70	$^\circ\text{C}/\text{W}$
$R_{\theta JC}$	Thermal Resistance Junction-Case ¹	36	$^\circ\text{C}/\text{W}$

Electrical Characteristics (T_A=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	V _{GS} =0V , I _D =-250uA	-60	---	---	V
ΔBVDSS / ΔT _J	BV _{DSS} Temperature Coefficient	Reference to 25°C , I _D =-1mA	---	-0.03	---	V/°C
RDS(ON)	Static Drain-Source On-Resistance	V _{GS} =-10V , I _D =-12A	---	55	70	mΩ
		V _{GS} =-4.5V , I _D =-8A	---	64	105	
VGS(th)	Gate Threshold Voltage	V _{GS} =V _{DS} , I _D =-250uA	-1.2	-1.5	-2.5	V
ΔVGS(th)	V _{GS(th)} Temperature Coefficient		---	4.56	---	mV/°C
IDSS	Drain-Source Leakage Current	V _{DS} =-48V , V _{GS} =0V , T _J =25°C	---	---	1	uA
		V _{DS} =-48V , V _{GS} =0V , T _J =55°C	---	---	5	
IGSS	Gate-Source Leakage Current	V _{GS} =±20V , V _{DS} =0V	---	---	±100	nA
gfs	Forward Transconductance	V _{DS} =-5V , I _D =-12A	---	15.4	---	S
R _g	Gate Resistance	V _{DS} =0V , V _{GS} =0V , f=1MHz	---	13.5	---	Ω
Q _g	Total Gate Charge (-4.5V)	V _{DS} =-48V , V _{GS} =-4.5V , I _D =-10A	---	9.86	---	nC
Q _{gs}	Gate-Source Charge		---	3.08	---	
Q _{gd}	Gate-Drain Charge		---	2.95	---	
Td(on)	Turn-On Delay Time	V _{DD} =-15V , V _{GS} =-10V , R _G =3.3Ω , I _D =-1A	---	28.8	---	ns
T _r	Rise Time		---	19.8	---	
Td(off)	Turn-Off Delay Time		---	60.8	---	
T _f	Fall Time		---	7.2	---	
C _{iss}	Input Capacitance	V _{DS} =-15V , V _{GS} =0V , f=1MHz	---	1447	---	pF
C _{oss}	Output Capacitance		---	97.3	---	
C _{rss}	Reverse Transfer Capacitance		---	70	---	
I _s	Continuous Source Current ^{1,5}	V _G =V _D =0V , Force Current	---	---	-18	A
ISM	Pulsed Source Current ^{2,5}		---	---	-36	A
VSD	Diode Forward Voltage ²	V _{GS} =0V , I _S =-1A , T _J =25°C	---	---	-1.2	V

Note :

- 1、The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3、The EAS data shows Max. rating . The test condition is V_{DD}=-25V,V_{GS}=-10V,L=0.1mH,I_{AS}=-26.6A
- 4、The power dissipation is limited by 150°C junction temperature
- 5、The data is theoretically the same as I_D and I_{DM} , in real applications , should be limited by total power dissipation.

Typical Characteristics

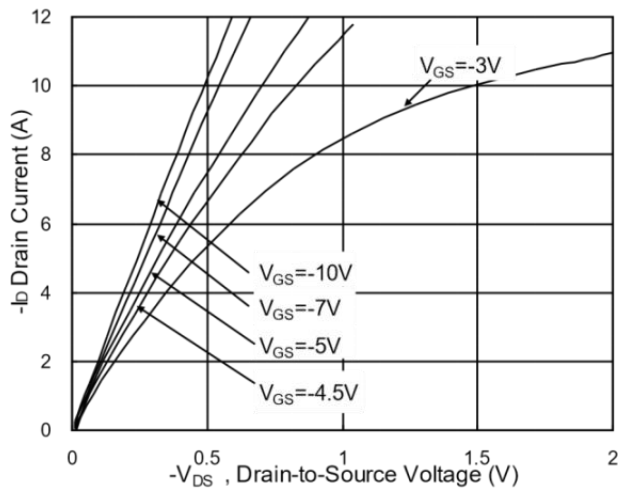


Fig.1 Typical Output Characteristics

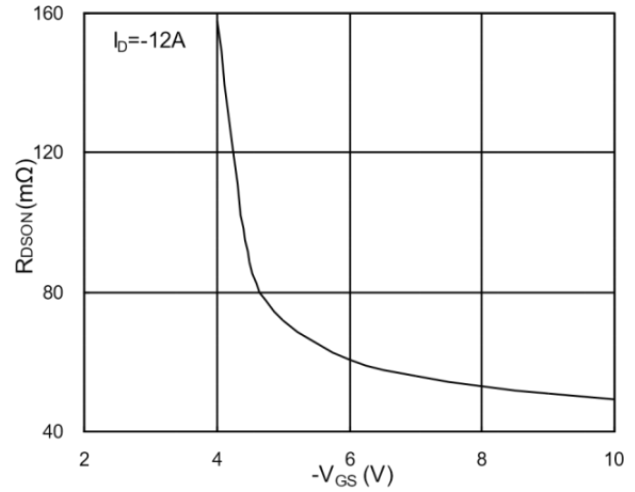


Fig.2 On-Resistance v.s Gate-Source

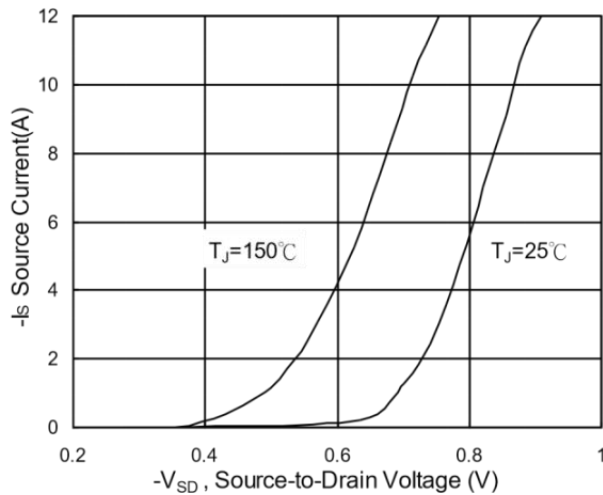


Fig.3 Forward Characteristics of Reverse

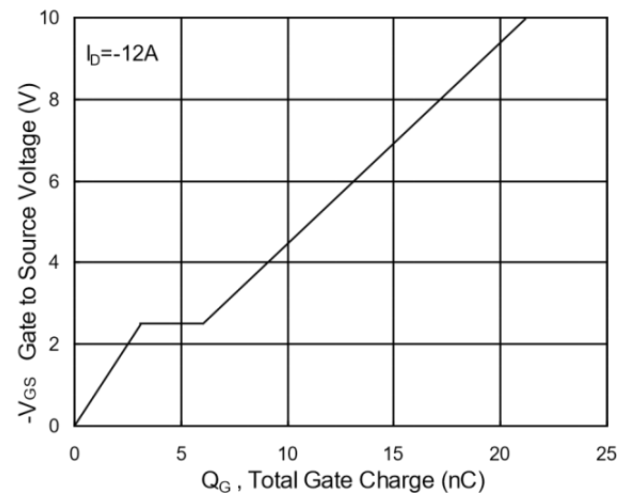


Fig.4 Gate-Charge Characteristics

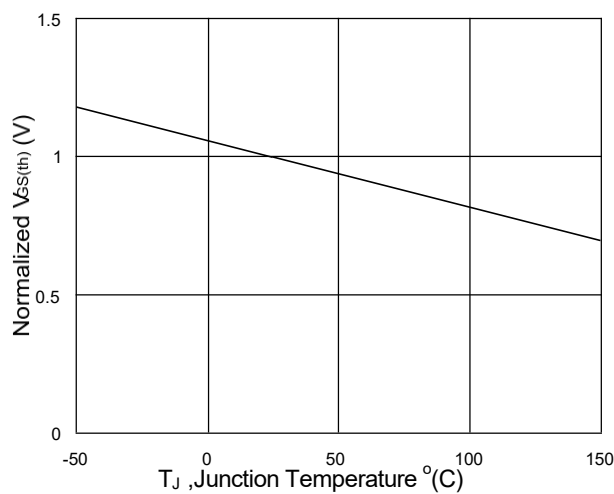


Fig.5 Normalized $V_{GS(th)}$ v.s T_J

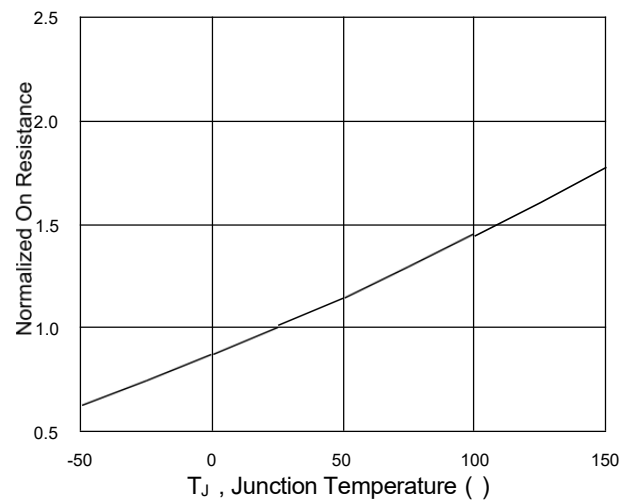
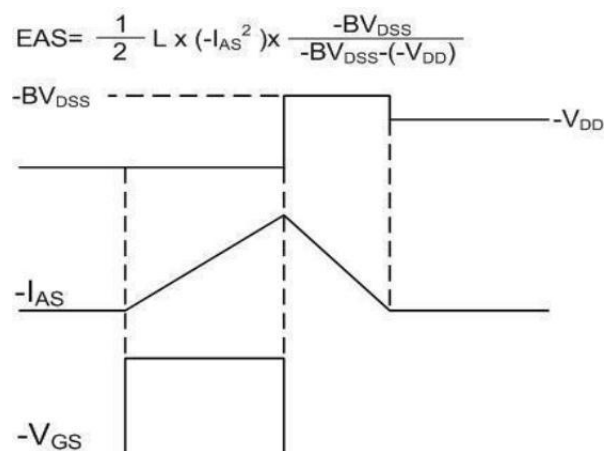
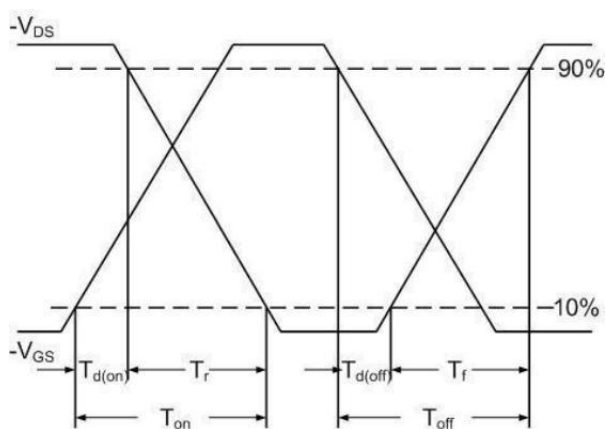
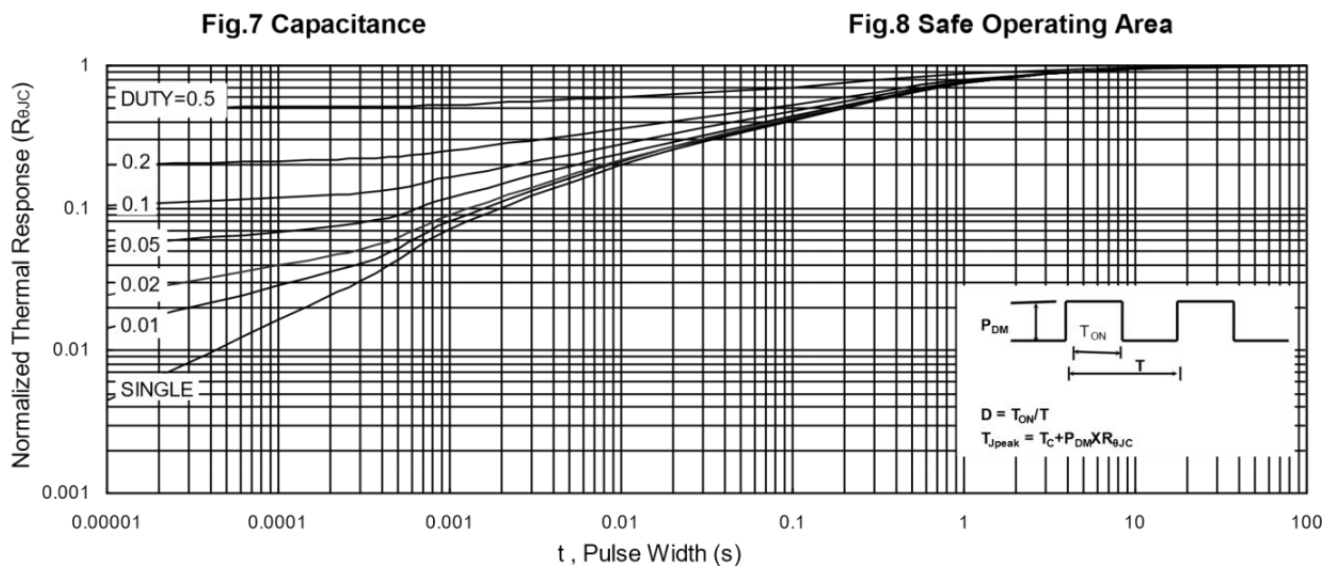
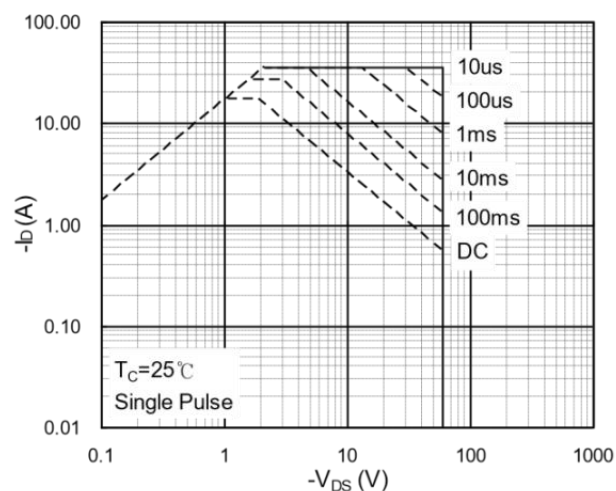
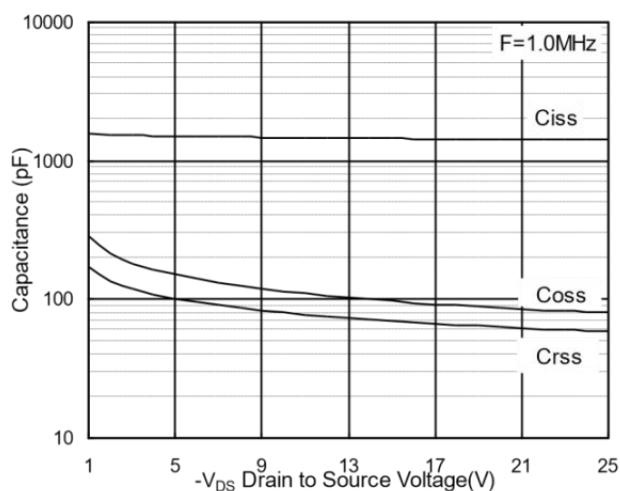
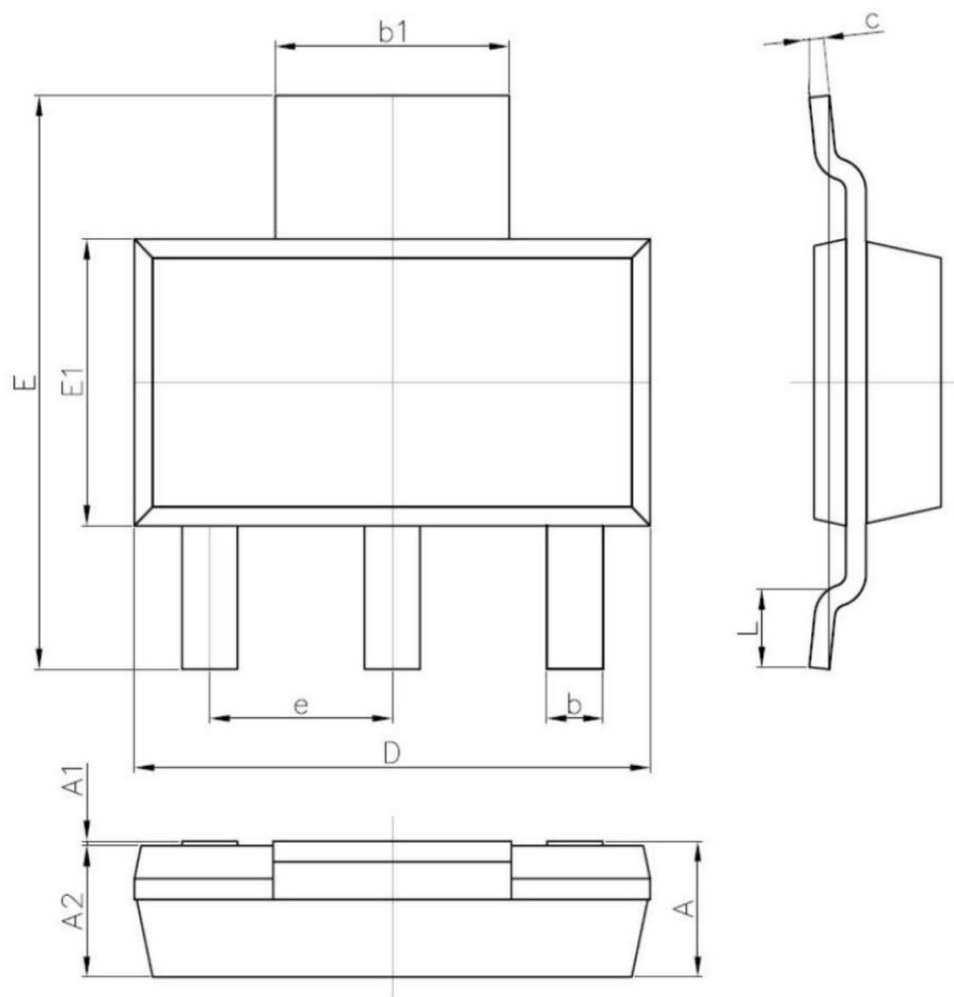


Fig.6 Normalized $R_{DS(on)}$ v.s T_J

Typical Characteristics



Package Mechanical Data:SOT223-3L


Symbol	Dim in mm	
	min.	max.
A	1.52	1.8
A1	0.02	0.1
A2	1.5	1.7
b	0.66	0.84
b1	2.9	3.1
c	0.23	0.35
D	6.3	6.7
E	6.7	7.3
E1	3.3	3.7
e	2.3(BSC)	
L	0.75	1.1

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	SOT223-3L		3000